

概述:

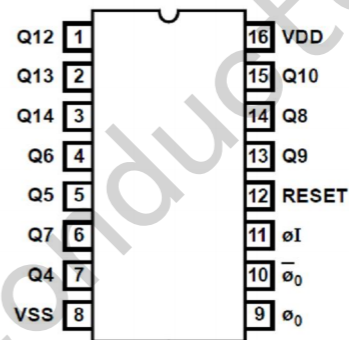
CD4060包含一个振荡器和一组十四位二进制串行计数器。震荡器的结构可以是RC或晶振电路。Reset为高电平时，计数器清零且振荡器使用无效，所有的计数器位均为主从触发器。在CP1（和CP0）的下降沿计数器以二进制进行计数，在时钟脉冲线上使用施密特触发器对时钟上升和下降时间无限制。

CD4060 提供了16 引线列塑料双列直插（BE）和塑料双列贴片（BM）2 种封装形式。

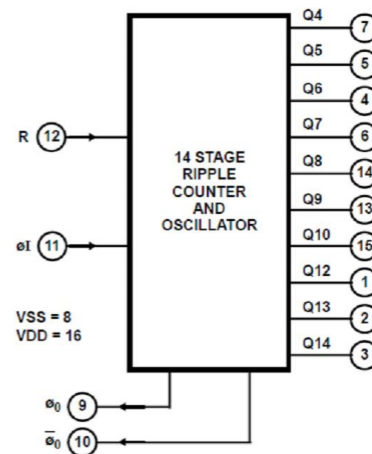
主要特点:

- 高达18V的电源（极限）
- 公共复位RESET
- 15V时输入可达12MHz
- 可全静态的工作
- 缓冲输入和输出
- 施密特触发输入脉冲
- 标准化，对称的输出特性
- 5V，10V，15V三个等级

引脚排列图:



功能框图:



振荡器特点:

- RC或晶体振荡器配置
- 在15V时，RC振荡器可达690kHz的频率

应用:

- 控制计数
- 定时器
- 分频器
- 时延电路

极限值: (Ta=25° C)

参数名称	符号	数值	单位
电源电压	Vdd	-0.5 to +18	V
工作电流	Idd	±10	mA
输入电压	V _{POL}	-0.5 to VDD +0.5	V
工作温度	T _{opr}	-40 to +85	° C
贮存温度	T _{stg}	-65 to +150	° C

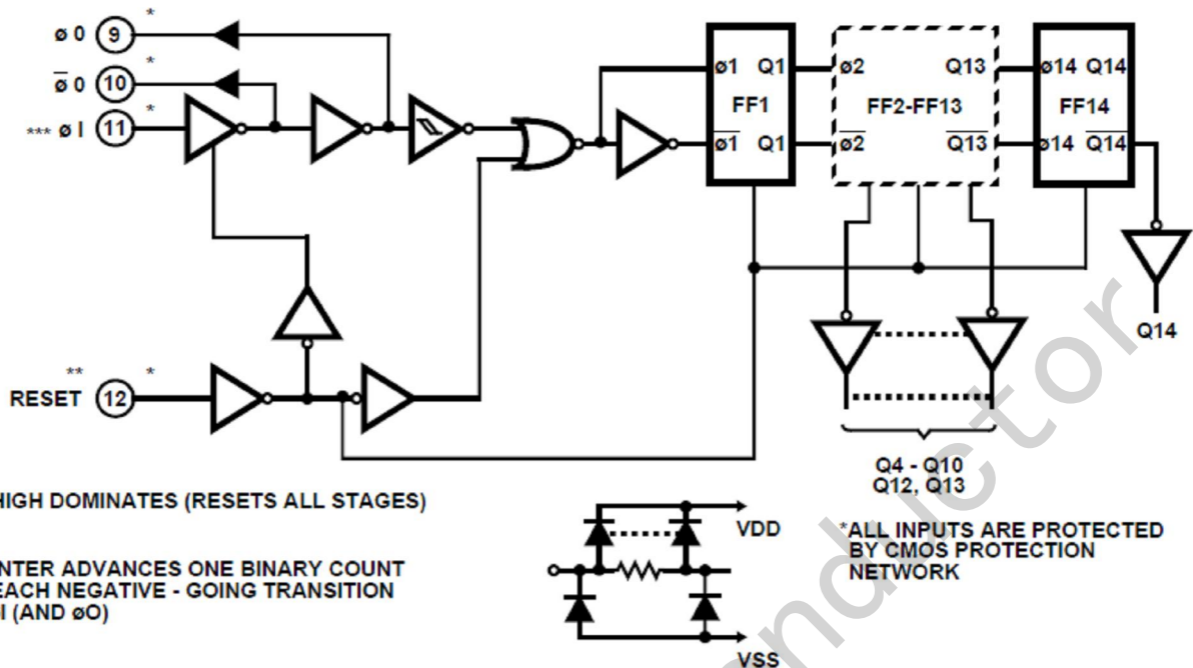
电气参数特性: (若无其它规定: $T_a = 25^{\circ}\text{C}$;)

PARAMETER	SYMBOL	CONDITIONS (NOTE 1)		TEMPERATURE ($^{\circ}\text{C}$)	LIMITS		UNITS
					MIN	MAX	
Supply Current	IDD	VDD = 18V, VIN = VDD or GND		+25	-	10	μA
Input Leakage Current	IIL	VIN = VDD or GND	VDD = 18V	+25	-300	-	nA
Input Leakage Current	IIH	VIN = VDD or GND	VDD = 18V	+25	-	300	nA
Output Voltage	VOL15	VDD = 15V, No Load		+25	-	50	mV
Output Voltage	VOH15	VDD = 15V, No Load (Note 3)		+25	14.95	-	V
Output Current (Sink) (Excluding pins 9 & 10)	IOL5	VDD = 5V, VOUT = 0.4V		+25	0.53	-	mA
	IOL10	VDD = 10V, VOUT = 0.5V		+25	1.4	-	mA
	IOL15	VDD = 15V, VOUT = 1.5V		+25	3.5	-	mA
Output Current (Source) (Excluding pins 9 & 10)	IOH5A	VDD = 5V, VOUT = 4.6V		+25	-	-0.53	mA
	IOH5B	VDD = 5V, VOUT = 2.5V		+25	-	-1.8	mA
	IOH10	VDD = 10V, VOUT = 9.5V		+25	-	-1.4	mA
	IOH15	VDD = 15V, VOUT = 13.5V		+25	-	-3.5	mA
N Threshold Voltage	VNTH	VDD = 10V, ISS = -10 μA		+25	-2.8	-0.7	V
P Threshold Voltage	VPTH	VSS = 0V, IDD = 10 μA		+25	0.7	2.8	V
Functional	F	VDD = 2.8V, VIN = VDD or GND		+25	VOH > VDD/2	VOL < VDD/2	V
		VDD = 18V, VIN = VDD or GND					
		VDD = 3V, VIN = VDD or GND					
Input Voltage Low (Note 2)	VIL	VDD = 5V, VOH > 4.5V, VOL < 0.5V		+25	-	1.5	V
Input Voltage High (Note 2)	VIH	VDD = 5V, VOH > 4.5V, VOL < 0.5V		+25	3.5	-	V
Input Voltage Low (Note 2)	VIL	VDD = 15V, VOH > 13.5V, VOL < 1.5V		+25	-	4	V
Input Voltage High (Note 2)	VIH	VDD = 15V, VOH > 13.5V, VOL < 1.5V		+25	11	-	V

- Notes: 1. All voltages referenced to device GND, 100% testing being implemented.
 2. Go/No Go test with limits applied to inputs.
 3. For accuracy, voltage is measured differentially to VDD. Limits 0.050V max.

PARAMETER	SYMBOL	CONDITIONS	TEMPERATURE (° C)	LIMITS		UNITS
				MIN	MAX	
Drive Current at Pin 9 Oscillator Design	IOL	VDD = 5V, VO = .4V	+25	0.16	-	mA
		VDD = 10V, VO = .5V	+25	0.42	-	mA
		VDD = 15V, VO = 1.5V	+25	-1.0	-	mA
Drive Current at Pin 9 Oscillator Design	IOH	VDD = 5V	+25	-	-.16	mA
		VDD = 10V	+25	-	-.42	mA
		VDD = 15V	+25	-	1.0	mA
Propagation Delay Input Pulse ϕ 1 to Q4	TPHL1	VDD = 10V	+25	-	300	ns
	TPLH1	VDD = 15V	+25	-	200	ns
Propagation Delay QN to QN + 1	TPHL2	VDD = 10V	+25	-	100	ns
	TPLH2	VDD = 15V	+25	-	80	ns
Propagation Delay RESET	TPHL3	VDD = 10V	+25	-	160	ns
		VDD = 15V	+25	-	100	ns
Transition Time	TTHL TTLH	VDD = 10V	+25	-	100	ns
		VDD = 15V	+25	-	80	ns
Maximum Input Pulse Frequency	F ϕ I	VDD = 10V	+25	8	-	MHz
		VDD = 15V	+25	12	-	MHz
Minimum RESET Pulse Width	TW	VDD = 5V	+25	-	120	ns
		VDD = 10V	+25	-	60	ns
		VDD = 15V	+25	-	40	ns
Minimum Input Pulse Width F = 100kHz	TW	VDD = 5V	+25	-	100	ns
		VDD = 10V	+25	-	40	ns
		VDD = 15V	+25	-	30	ns
RC Operation RX Max	RX	VDD = 5V, CX = 10 F	+25	-	20	M Ω
		VDD = 10V, CX = 50 F	+25	-	20	M Ω
		VDD = 15V, CX = 10 F	+25	-	10	M Ω
RC Operation CX Max	CX	VDD = 5V, RX = 500k Ω	+25	-	1000	F
		VDD = 10V, RX = 300k Ω	+25	-	50	F
		VDD = 15V, RX = 300k Ω	+25	-	50	F
Maximum Oscillator Frequency (Note 4)	RX = 5k Ω	VDD = 10V	+25	530	810	ns
	CX = 15pF	VDD = 15V	+25	690	940	ns
RC Operation Variation of Frequency (Unit-to-Unit)	CX = 200pF	VDD = 5V	+25	18	25	kHz
	RS = 560K	VDD = 10V	+25	20	26	kHz
	RX = 50k	VDD = 15V	+25	21.1	27	kHz
Variation of Frequency with Voltage Change	CX = 200pF	5V to 10V	+25	-	2	kHz
	RS = 560K	10V to 15V	+25	-	1	kHz
Input Capacitance	CIN	Any Input	+25	-	7.5	pF

内部框图:



特性曲线:

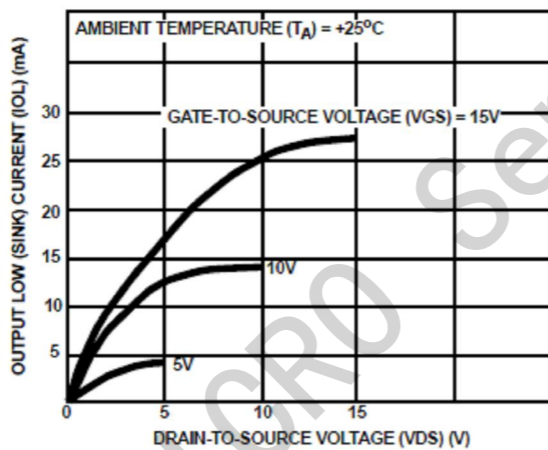


FIGURE 1. TYPICAL N-CHANNEL OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

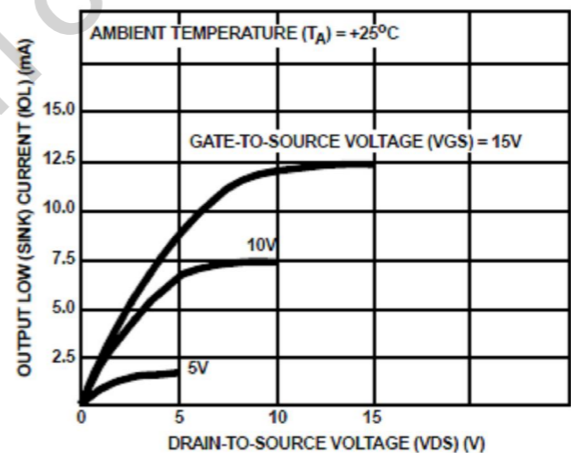


FIGURE 2. MINIMUM N-CHANNEL OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

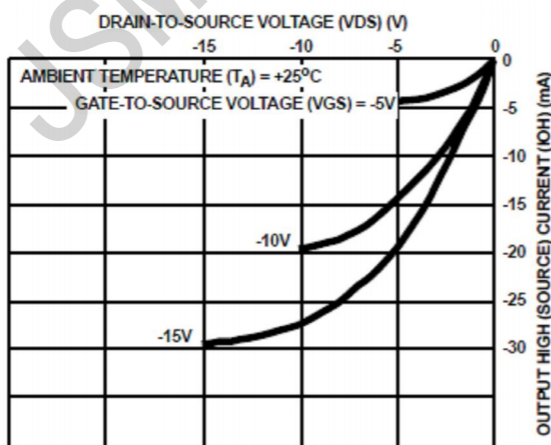


FIGURE 3. TYPICAL P-CHANNEL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

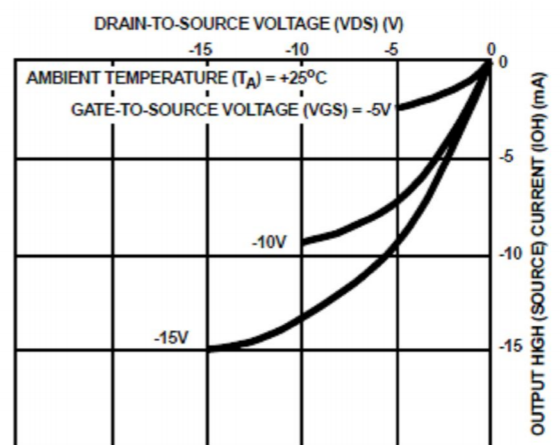


FIGURE 4. MINIMUM P-CHANNEL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

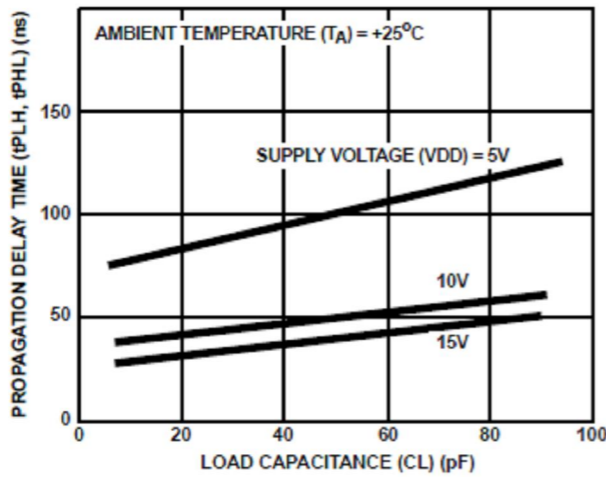


FIGURE 5. TYPICAL PROPAGATION DELAY TIME (QN TO QN+1) AS A FUNCTION OF LOAD CAPACITANCE

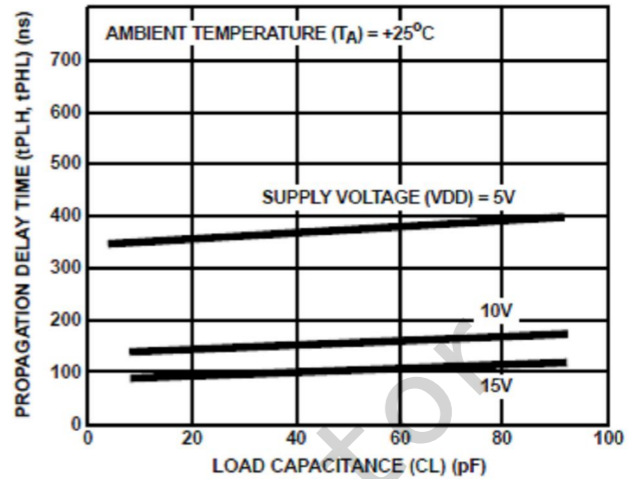


FIGURE 6. TYPICAL PROPAGATION DELAY TIME (Q1 TO Q4 OUTPUT) AS A FUNCTION OF LOAD CAPACITANCE

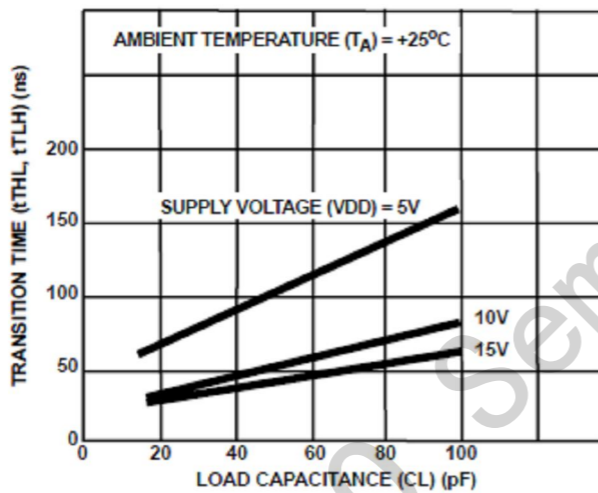


FIGURE 7. TYPICAL TRANSITION TIME AS A FUNCTION OF LOAD CAPACITANCE

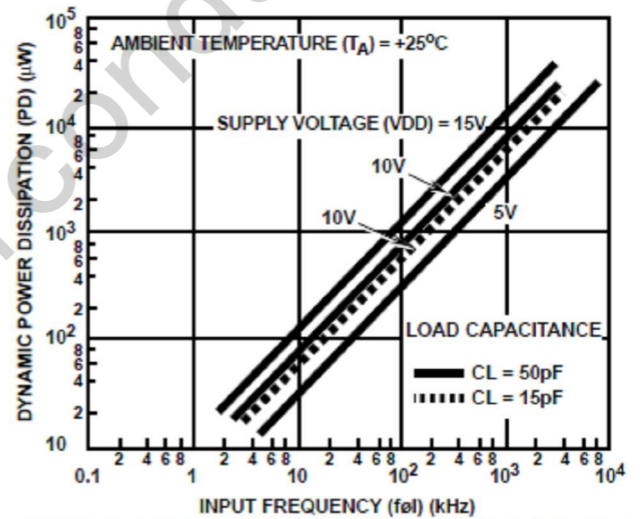


FIGURE 8. TYPICAL DYNAMIC POWER DISSIPATION AS A FUNCTION OF INPUT FREQUENCY

测试电路:

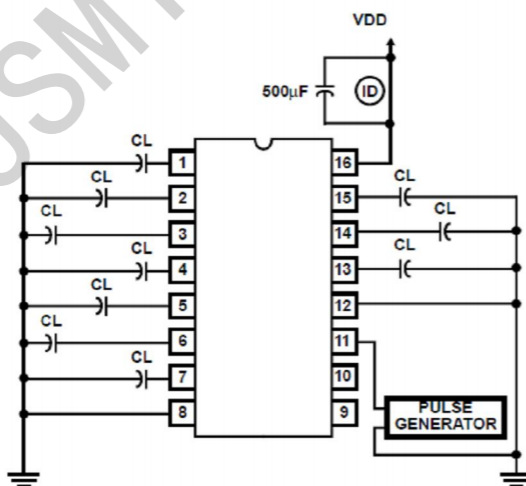


FIGURE 9. DYNAMIC POWER DISSIPATION TEST CIRCUIT

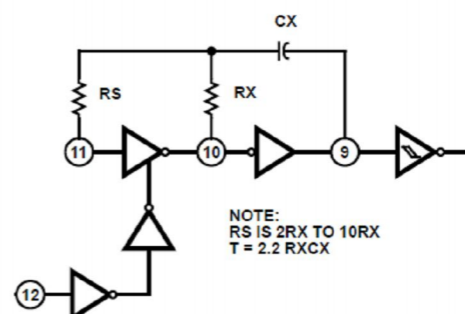
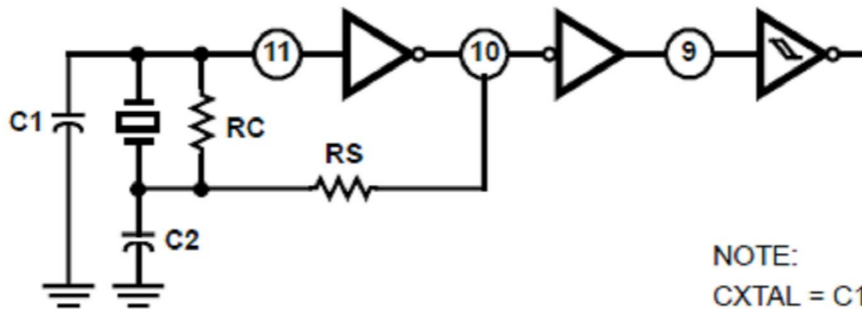


FIGURE 10. TYPICAL RC CIRCUIT



NOTE:
CXTAL = C1 + C2 + CSTRAY
RC = Broader frequency response
RS = Current limiting

FIGURE 11. TYPICAL CRYSTAL CIRCUIT

封装信息

